

## T495X476K025ATA800

T495 Auto, Tantalum, MnO2 Tantalum, Commercial Grade, 47 uF, 10%, 25 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 800 mOhms, 7343, 4.3 mm, 1.3 mm

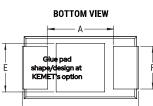
CATHODE (-) END VIEW



ANODE (+) END VIEW

SIDE VIEW





Click here for the 3D model.

General Information	
Series	T495 Auto
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200
Features	Low ESR, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	652.04 mg

Specifications	
Capacitance	47 uF
Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	800 mOhms (100kHz 25C)
Ripple Current	454 mA (rms, 100kHz 25C), 408.6 mA (rms, 85C), 181.6 mA (rms, 125C)
Leakage Current	11.6 uA (5min 25°C)

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
н	4mm +/-0.3mm
т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
Α	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	1.7mm REF
R	1mm REF
х	0.1mm +/-0.1mm REF

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

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